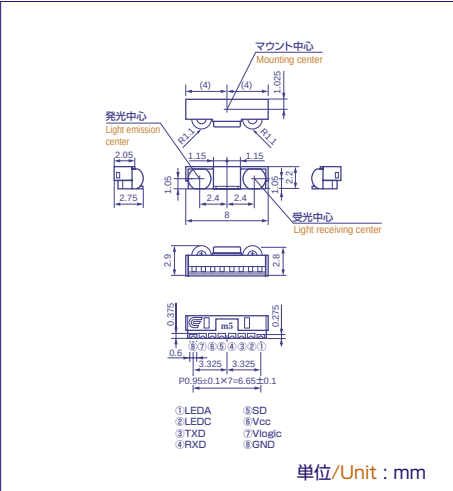


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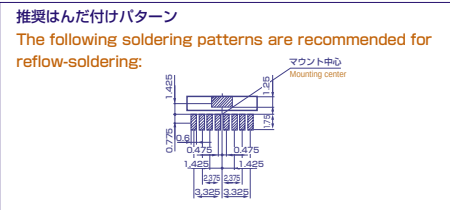


外形寸法図/Outline drawing

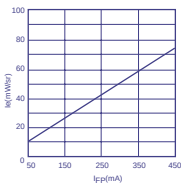


電氣的光学的特性/Electro-optical characteristics (Ta 25℃)

Item	Symbol	Conditions	Min	Typ	Max	Unit
トランシーバー Transceiver	電源電圧 Power supply voltage	V _{CC}	-	2.4	-	3.6 V
	供給電圧 Power supply voltage	V _{logic}	-	1.5	-	V _{CC} V
	通信レート Communications rate	-	-	0.0096	-	1.152 Mbps
	消費電流 Current drawn	I _{CC}	No Load	-	445	550 μA
	Power Down電流 Power-down current	I _{CCSD}	SD=V _{CC}	-	0.01	1 μA
発光部 Light emitting portion	放射強度 Emission strength	I _e	V _{CC} =Anode=4.4V R _L =5Ω I _F ≒380mA	40	-	200 mW/sr
	ピーク発光波長 Peak emission wavelength	λ _p	-	850	875	900 nm
受光部 Light sensing portion	最小受光感度 Minimum receiving sensitivity	E _{emin}	0.576Mbps 1.152Mbps	-	5.0	8.0 μW/cm ²
	最大受光感度 Maximum receiving sensitivity	E _{emax}	α=0°	500	-	- mW/cm ²
	レイテンシー Latency	T _L	-	-	50	100 μs



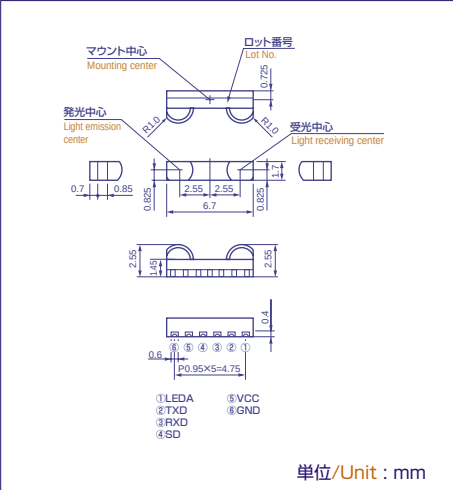
諸特性/Characteristics



CIM-130M7

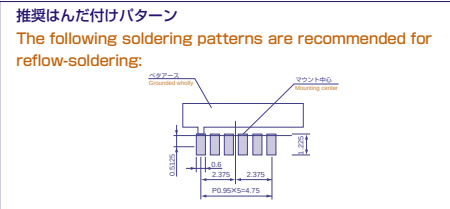


外形寸法図/Outline drawing



電氣的光学的特性/Electro-optical characteristics (Ta 25℃)

Item	Symbol	Conditions	Min	Typ	Max	Unit
トランシーバー Transceiver	電源電圧 Power supply voltage	V _{CC}	-	2.4	-	3.6 V
	供給電圧 Power supply voltage	V _{logic}	-	1.5	-	V _{CC} V
	通信レート Communications rate	-	-	0.0096	-	1.152 Mbps
	消費電流 Current drawn	I _{CC}	No Load	-	445	550 μA
	Power Down電流 Power-down current	I _{CCSD}	SD=V _{CC}	-	0.01	1 μA
発光部 Light emitting portion	放射強度 Emission strength	I _e	V _{CC} =Anode=4.4V R _L =5Ω I _F ≒380mA	40	-	200 mW/sr
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	最大受光感度 Maximum receiving sensitivity	E _{emax}	α=0°	500	-	- mW/cm ²
	レイテンシー Latency	T _L	-	-	50	100 μs



諸特性/Characteristics

